Freeform Search

US Pre-Grant Publication Full-Text Database US Patents Full-Text Database US OCR Full-Text Database Database: EPO Abstracts Database JPO Abstracts Database Derwent World Patents Index IBM Technical Disclosure Bulletins L15 and (switch\$3 near sens\$3 near reference or switch\$3 junctions or switch\$3 diodes or switch\$3 Term: transistors or switch\$3 semiconductors switch\$3 Documents in Display Format: |- Starting with Number 1 Display: 10 Generate: O Hit List @ Hit Count O Side by Side O Image Search Clear

Search History

DATE: Thursday, April 12, 2007 Purge Queries Printable Copy Create Case

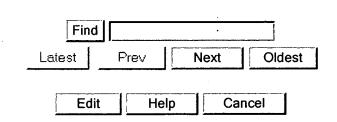
Set Name side by side	Query	<u>Hit</u> Count	Set Name result set
DB=	=PGPB,USPT,USOC,EPAB,JPAB; PLUR=YES; OP=ADJ		
<u>L24</u>	L15 and (alternat\$3 diodes or alternat\$3 junction)	10	<u>L24</u>
<u>L23</u>	L15 and (alretnat\$3 diodes or alternat\$3 junction)	2	<u>L23</u>
<u>L22</u>	L15 and (switch\$3 near sens\$3 near reference or switch\$3 junctions or switch\$3 diodes or switch\$3 transistors or switch\$3 semiconductors switch\$3 sensors)	168	<u>L22</u>
<u>L21</u>	L15 and (multiplex\$3 near sens\$3 near reference or multiplex\$3 junctions or multiplex\$3 diodes or multiplex\$3 transistors or multiplex\$3 semiconductors)	1	<u>L21</u>
<u>L20</u>	L15 and (switch\$3 near sens\$3 near reference)	0	<u>L20</u>
<u>L19</u>	L15 and (two sens\$3 near configuration or dual sens\$3 near configuration)	3	<u>L19</u>
<u>L18</u>	L15 and (two diode configuration or two junction configuration or two transistor configuration)	4	<u>L18</u>
<u>L17</u>	L15 and (two diode confifuration or two junction configuration or two transistor configuration)	2	<u>L17</u>
<u>L16</u>	L15 and (dual diode or dual near junction)	12	<u>L16</u>
<u>L15</u>	(374/170,171,172,173,178,183;327/512,513;702/130,99,133)![CCLS]	4559	<u>L15</u>
$DB^{=}$	=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ		

<u>L14</u>	L13 and (reference diode or dual diode or two near diode)	153	<u>L14</u>
<u>L13</u>	702/\$.ccls.	43761	<u>L13</u>
<u>L12</u>	L11 and (switch\$3 or multiplex\$3)	44	<u>L12</u>
<u>L11</u>	327/512 and (reference diode or dual diode or two near diode)	62	<u>L11</u>
<u>L10</u>	357/512 and (reference diode same switch\$3)	0	<u>L10</u>
<u>L9</u>	L7 and (reference diode same multiplex\$3)	0	<u>L9</u>
<u>L8</u>	L7 and (reference diode same switch\$3)	6	<u>L8</u>
<u>L7</u>	374/\$.ccls.	29556	<u>L7</u>
<u>L6</u>	dual near sensor same multiplex\$3	26	<u>L6</u>
<u>L5</u>	dual near transistor same multiplex\$3	6	<u>L5</u>
<u>L4</u>	dual near diode same multiplex\$3	14	<u>L4</u>
<u>L3</u>	L1 and (dual near sensor near switch\$3 or dual near sensor near multiplex\$3)	. 0	<u>L3</u>
<u>L2</u>	L1 and (switch\$3 near sensors or multiplex\$3 sensors)	111	<u>L2</u>
L1	374/\$.ccls.	29556	L1

END OF SEARCH HISTORY

Searches for User *gverbitsky* (Count = 48185)

Queries 48136 through 48185.



S# Upd	t Database	Query
•	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (alternat\$3 diodes or altern
<u>S48184</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (alretnat\$3 diodes or alterr
<u>S48183</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (switch\$3 near sens\$3 near switch\$3 junctions or switch\$3 diodes or or switch\$3 semiconductors switch\$3 semiconductors.
<u>S48182</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (multiplex\$3 near sens\$3 1 multiplex\$3 junctions or multiplex\$3 dic transistors or multiplex\$3 semiconductor
<u>S48181</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (switch\$3 near sens\$3 near
<u>S48180</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (two sens\$3 near configuration)
<u>S48179</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (two diode configuration o configuration or two transistor configura
<u>S48178</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (two diode configuration or configuration or two transistor configura
<u>S48177</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	((374/170,171,172,173,178,183;327/512 [CCLS]) and (dual diode or dual near ju
<u>S48176</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB	(374/170,171,172,173,178,183;327/512, [CCLS]
<u>S48175</u> <u>U</u>	PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBI	D (702/\$.ccls.) and (reference diode or duadiode)

S48174 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD702/\$.ccls. S48173 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD(327/512 and (reference diode or dua diode)) and (switch\$3 or multiplex\$ S48172 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD327/512 and (reference diode or dua diode) S48171 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD327 and (reference diode or dual dio diode) S48170 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD357/512 and (reference diode same states of the diodes of dual diodes dio
diode)) and (switch\$3 or multiplex\$ S48172 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD327/512 and (reference diode or dual diodes and dio
S48171 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD 327 and (reference diode or dual diodes and section of the section
S48169 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD 357/512 and (reference diode same serior s
S48169 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (reference diode states of the states
S48168 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (reference diode standard stan
S48167 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD 374/\$.ccls. S48166 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near sensor same multiplex\$3 S48165 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near transistor same multiplex\$ S48164 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near diode same multiplex\$ S48163 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (dual near sensor)
S48166 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near sensor same multiplex\$3 S48165 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near transistor same multiplex\$ S48164 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near diode same multiplex\$3 S48163 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (dual near sensor)
S48165 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near transistor same multiplex\$ S48164 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near diode same multiplex\$3 S48163 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (dual near sensor)
S48164 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD dual near diode same multiplex\$3 S48163 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (dual near sensor)
S48163 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (dual near sensor)
S48162 U PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD (374/\$.ccls.) and (switch\$3 near ser sensors)
S48161 <u>U</u> PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD374/\$.ccls.
<u>S48160</u> <u>U</u> USPT 4137049.pn.
<u>S48159</u> <u>U</u> USPT 5215378.pn.